### TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# 2 S C 5 1 0 8

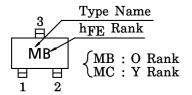
### FOR VCO APPLICATION

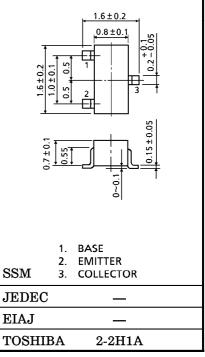
## Unit in mm

### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Collector-Base Voltage	$v_{CBO}$	20	V	
Collector-Emitter Voltage	$v_{CEO}$	10	V	
Emitter-Base Voltage	$V_{ m EBO}$	3	V	
Base Current	$I_{\mathbf{B}}$	15	mA	
Collector Current	$_{ m I_C}$	30	mA	
Collector Power Dissipation	$P_{\mathbf{C}}$	100	mW	
Junction Temperature	$T_{j}$	125	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$	

### **MARKING**





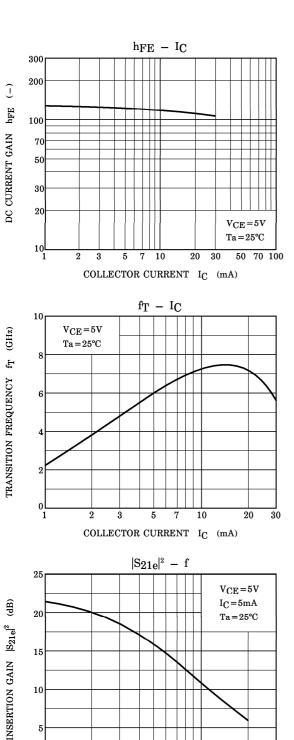
Weight: 2.4mg

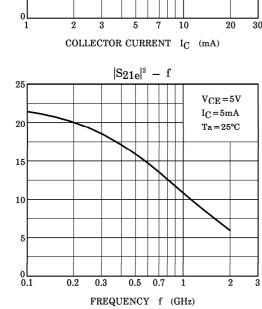
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

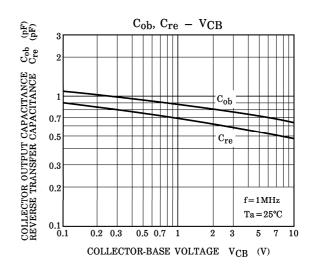
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 10V, I_{E} = 0$	_	_	0.1	$\mu$ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=1V, I_{C}=0$	_	_	0.1	$\mu$ A
DC Current Gain	h <sub>FE</sub> (Note 1)	$V_{CE}=5V, I_{C}=5mA$	80	_	240	_
Transition Frequency	$ m f_{T}$	$V_{CE}=5V, I_{C}=5mA$	4	6	_	GHz
Insertion Gain	$ \mathrm{S}_{21\mathrm{e}} ^2$	$V_{CE}=5V$ , $I_{C}=5mA$ , $f=1GHz$	7	11	_	dB
Output Capacitance	$C_{\mathbf{ob}}$	$V_{CB} = 5V, I_E = 0, f = 1MHz$	_	0.7	_	pF
Reverse Transfer Capacitance	$\mathrm{c_{re}}$	(Note 2)	_	0.5	0.9	pF
Collector-Base Time Constant	C <sub>c</sub> .rbb'	$V_{CB}=5V$ , $I_{C}=3mA$ , $f=30MHz$	_	5.5	10	ps

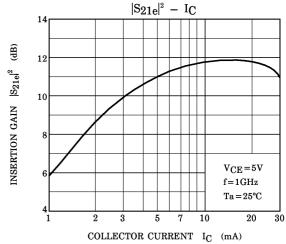
(Note 1) hFE Classification O:80~160, Y:120~240 (Note 2)  $C_{re}$  is measured by 3 terminal method with capacitance bridge.

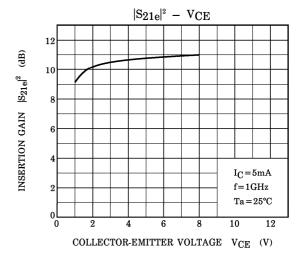
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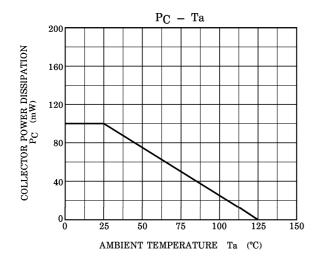








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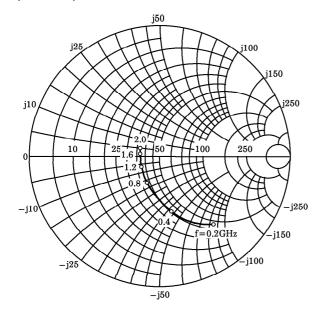
S-Parameter  $Z_O = 50\Omega$ ,  $Ta = 25^{\circ}C$   $V_{CE} = 5V$ ,  $I_C = 5mA$ 

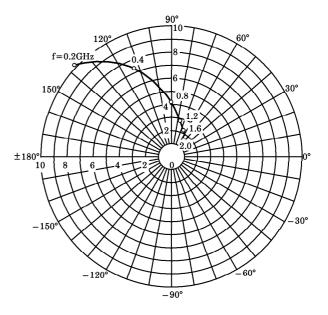
frequency	S11		S21		S12		S22	
(MHz)	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.	Mag.	Ang.
200	0.684	-47.0	10.116	136.8	0.049	63.1	0.765	-29.5
400	0.438	-79.2	7.260	112.9	0.072	56.5	0.553	-37.8
600	0.301	-101.2	5.388	99.1	0.090	56.5	0.452	-39.1
800	0.226	-119.2	4.227	90.0	0.107	57.6	0.402	-39.0
1000	0.182	-136.2	3.494	82.7	0.124	58.8	0.374	-38.9
1200	0.159	-153.3	2.988	76.9	0.142	59.6	0.359	-39.4
1400	0.147	-170.3	2.632	71.2	0.163	59.9	0.348	-40.7
1600	0.145	174.4	2.345	66.0	0.182	59.2	0.339	-43.2
1800	0.149	162.6	2.128	61.4	0.200	58.4	0.329	-46.3
2000	0.161	150.9	1.967	57.1	0.219	58.1	0.318	-49.5

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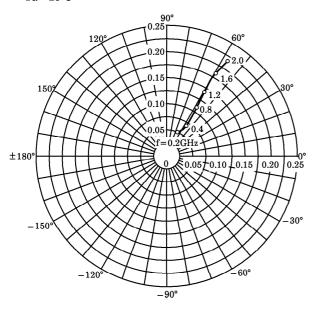
 $\begin{array}{l} S_{11e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ Ta = 25^{\circ}C \\ (UNIT:\Omega) \end{array}$ 







 $S_{12e}$   $V_{CE} = 5V$   $I_{C} = 5mA$  $T_{a} = 25^{\circ}C$ 



 $\begin{array}{c} S_{22e} \\ V_{CE} = 5V \\ I_{C} = 5mA \\ T_{a} = 25^{\circ}C \\ (UNIT:\Omega) \\ \\ j_{25} \\ 0 \\ 0 \\ 10 \\ 25 \\ 50 \\ 100 \\ 250 \\ 0.4 \\ f = 0.2 \\ GHz \\ -j250 \\ -j150 \\ \\ -j150 \\ \end{array}$ 

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-j50

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